3 1. The magneto-optical device of Claim 10, wherein said side walls are perpendicular to a surface of said substrate.

 ψ 12. The magneto-optical device of Claim 9, further comprising a reflecting layer on a first face of said substrate.

5 13. The magneto-optical device of Claim 12, further comprising an anti-reflecting layer on a second face of said substrate.

The magneto-optical device of Claim 9, wherein said ferromagnetic layers are electrically conductive.

The magneto-optical device of Claim 14, wherein said ferromagnetic layers comprise particles of a member of the group consisting of Fe, Co, Ni, FeCo alloys, FeNi alloys and CoNi alloys.

The magneto-optical device of Claim 15, wherein said ferromagnetic layers have an average diameter in an inclusive range of 2 through 20 nanometers.

9 17. The magneto-optical device of Claim 9, further comprising a layer of non-magnetic semiconducting material or metal in contact with said ferromagnetic layers and having a same thickness as the thickness of the ferromagnetic layers and a width in an inclusive range of 5 through 10 nanometers.

The magneto-optical device of Claim 10, further comprising a reflecting layer on a first face of said substrate.

The magneto-optical device of Claim 18, further comprising an anti-reflecting layer on a second face of said substrate.

120. The magneto-optical device of Claim 10, wherein said ferromagnetic layers are electrically conductive.

13 21. The magneto-optical device of Claim 20, wherein said ferromagnetic layers comprise particles of a member of the group consisting of Fe, Co, Ni, FeCo alloys, FeNi alloys and CoNi alloys.

The magneto-optical device of Claim 2/1, wherein said ferromagnetic layers have an average diameter in an inclusive range of 2 through 20 nanometers.

The magneto-optical device of Claim 10, further comprising a layer of non-magnetic semiconducting material or metal in contact with said ferromagnetic layers and having a same thickness as the thickness of the ferromagnetic layers and a width in an inclusive range of 5 through 10 nanometers.

1624. The magneto-optical device of Claim 1/1, further comprising a reflecting layer on a first face of said substrate.

17 28. The magneto-optical device of Claim 24, further comprising an anti-reflecting layer on a second face of said substrate.

The magneto-optical device of Claim 11, wherein said ferromagnetic layers are electrically conductive.

The magneto-optical device of Claim 26, wherein said ferromagnetic layers comprise particles of a member of the group consisting of Fe, Co, Ni, FeCo alloys, FeNi alloys and CoNi alloys.

The magneto-optical device of Claim 2/1, wherein said ferromagnetic layers have an average diameter in an inclusive range of 2 through 20 nanometers.

The magneto-optical device of Claim 17, further comprising a layer of non-magnetic semiconducting material or metal in contact with said ferromagnetic layers and